### PRELIMINARY DATASHEET

# **VERSACLOCK<sup>®</sup> LOW POWER CLOCK GENERATOR**

### **IDT5P49EE601**

### Description

The IDT5P49EE601 is a programmable clock generator intended for low power, battery operated consumer applications. There are four internal PLLs, each individually programmable, allowing for up to six differrent output frequencies. The frequencies are generated from a single reference clock. The reference clock can come from either a TCXO or fundamental mode crystal. An additional 32.768kHz crystal oscillator is available to provide a real time clock or non-critical performance MHz processor clock.

The IDT5P49EE601 can be programmed through the use of the  $I^2C$  interfaces. The programming interface enables the device to be programmed when it is in normal operation or what is commonly known as in system programmable. An internal EEPROM allows the user to save and restore the configuration of the device without having to reprogram it on power-up.

Each of the four PLLs has an 8-bit reference divider and a 11-bit feedback divider. This allows the user to generate four unique non-integer-related frequencies. The PLL loop bandwidth is programmable to allow the user to tailor the PLL response to the application. For instance, the user can tune the PLL parameters to minimize jitter generation or to maximize jitter attenuation.

Spread spectrum generation is supported on one of the PLLs. The device is specifically designed to work with display applications to ensure that the spread profile remains consistent for each HSYNC in order to reduce ROW noise.

There are total six 8-bit output dividers. One output bank can be configured to support LVTTL or LVDS. All other outputs are always set to LVTTL. The outputs are connected to the PLLs via the switch matrix. The switch matrix allows the user to route the PLL outputs to any output bank. This feature can be used to simplify and optimize the board layout. In addition, each output's slew rate and enable/disable function can be programmed.

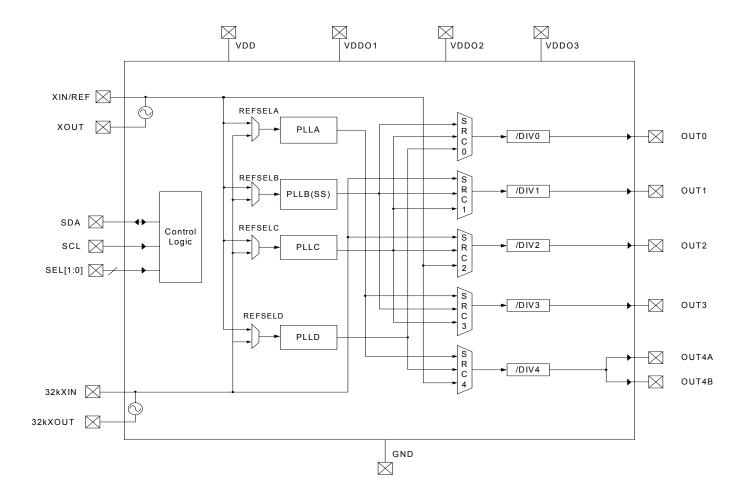
### **Target Applications**

- Smart Mobile Handset
- Personal Navigation Device (PND)
- Camcorder
- DSC
- Portable Game Console
- Personal Media Player

### **Features**

- Four internal PLLs
- Internal non-volatile EEPROM
  - Internal I<sup>2</sup>C EEPROM master interface
- FAST (400kHz) mode I<sup>2</sup>C serial interfaces
- Input Frequencies
  - TCXO: 10 MHz to 40 MHz
  - Crystal: 8 MHz to 30 MHz
  - RTC Crystal: 32.768 kHz
- Output Frequency Ranges: kHz to 120 MHz
- Each PLL has an 8-bit reference divider and a 11-bit feedback-divider
- 8-bit output-divider blocks
- One of the PLLs support Spread Spectrum generation capable of configuration to pixel rate, with adjustable modulation rate and amplitude to support video clock with no visible artifacts
- I/O Standards:
   Outputs 1.8V/2.5V/3.3 V LVTTL/ LVCMOS
   Outputs 1 pair selectable 3.3V LVDS
- 3 independent adjustable VDDO groups.
- Programmable Slew Rate Control
- Programmable Loop Bandwidth Settings
- · Programmable output inversion to reduce bimodal jitter
- Individual output enable/disable
- Power-down/Sleep mode
  - 10µA max in power down mode
  - 32kHz clock output active sleep mode
  - 100µA max in sleep mode
- 1.8V VDD Core Voltage
- Available in 24pin 4x4mm QFN packages
- -40 to +85 C Industrial Temp operation

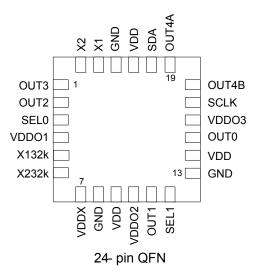
### **Functional Block Diagram**



Note 1: OUT4A & OUT4B pair can be configured to be LVDS or two single-ended LVTTL outputs.

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# **Pin Assignment**



### **Pin Descriptions**

Pin Name	Pin #	I/O	Pin Type	Pin Description
OUT3	1	0	Adjustable	Configurable clock output 3. Single-ended output voltage levels are register controlled by either VDDO1, VDDO2 or VDDO3.
OUT2	2	0	Adjustable	Configurable clock output 2. Single-ended output voltage levels are register controlled by either VDDO1, VDDO2 or VDDO3.
SEL0	3	I	LVTTL	Configuration select pin. Weak internal pull down resistor.
VDDO1	4		Power	Device power supply. Connect to 1.8 to 3.3V. Using register settings, select output voltage levels for OUT0-OUT4. VDDO1 must be greater than or equal to both VDDO2 and VDDO3.
X132k	5	I	LVTTL	32kHz CRYSTAL_IN Reference crystal input
X232k	6	0	LVTTL	32kHz CRYSTAL_OUT Reference crystal feedback.
VDDx	7		Power	Crystal oscillator power supply. Connect to 1.8V. Use filtered analog power supply if available.
GND	8		Power	Connect to Ground.
VDD	9		Power	Device power supply. Connect to 1.8V.
VDDO2	10		Power	Device power supply. Connect to 1.8 to 3.3V. Using register settings, select output voltage levels for OUT0-OUT4. VDDO2 must be equal or less than VDDO1.
OUT1	11	0	Adjustable	Configurable clock output 1. Single-ended output voltage levels are register controlled by either VDDO1, VDDO2 or VDDO3.
SEL1	12	I	LVTTL	Configuration select pin. Weak internal pull down resistor.

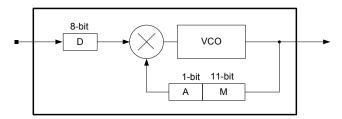
GND	13		Power	Connect to Ground.	
VDD	14		Power	Device power supply. Connect to 1.8V.	
OUT0	15	0	Adjustable	Configurable clock output 0. Single-ended output voltage levels are register controlled by either VDDO1, VDDO2 or VDDO3.	
VDDO3	16		Power	Device power supply. Connect to 1.8 to 3.3V. Using register settings, select output voltage levels for OUT0-OUT4. VDDO3 must be equal or less than VDDO1.	
SCLK	17	Ι	LVTTL	I <sup>2</sup> C clock.	
OUT4B	18	0	Adjustable	<ul> <li>Configurable clock output 4B. Single-ended or differential who combined with OUT4A. Output voltage levels are controlled b VDDO1.</li> </ul>	
OUT4A	19	0	Adjustable	Configurable clock output 4A. Single-ended or differential when combined with OUT4B. Output voltage levels are controlled by VDDO1.	
SDA	20	I/O	Open Drain	Bidirectional I <sup>2</sup> C data.	
VDD	21		Power	Device power supply. Connect to 1.8V.	
GND	22		Power	Connect to Ground.	
XIN/ REF	23	I	LVTTL	MHz CRYSTAL_IN Reference crystal input or external reference clock input.	
XOUT	24	0	LVTTL	MHz CRYSTAL_OUT Reference crystal feedback.	

Note 1: Outputs are user programmable to drive single-ended 1.8V/2.5V/3.3V LVTTL. Differential LVDS interface levels can be generated for OUT4A/OUT4B when connected to VDDO1=3.3V and registers configured appropriately. Alway completely power up VDD and VDDx prior to applying VDDO power.

Note 2: Default configuration CLK1=Buffered MHz Reference output and CLK2=Buffered 32.768kHz output. All other outputs are off.

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### PLL Features and Descriptions



#### **PLL Block Diagram**

	Ref-Divider (D) Values	Feedback Pre-Divider (XDIV) Values	Feedback (M) Values	Programmable Loop Bandwidth	Spread Spectrum Generation Capability
PLLA	1 - 255	1 or 4 <sup>1</sup>	6 - 2047	Yes	No
PLLB	1 - 255	4	6 - 2047	Yes	Yes
PLLC	1 - 255	1 or 8 bit divide <sup>2</sup>	6 - 2047	Yes	No
PLLD	1 - 255	1 or 4 <sup>1</sup>	6 - 2047	Yes	No

1.XDIVA or XDIVD=0, A=1. XDIVA or XDIVD=1, A=4.

2.XDIVC =0, A=1. XDIVC=1 turns on 8 bit predivide multiplier, A=FBC2[7:0]. Total feedback divide equals FBC[10:0] \*FBC2[7:0].

### **Crystal Input (XIN/REF)**

The crystal oscillators should be fundamental mode quartz crystals; overtone crystals are not suitable. Crystal frequency should be specified for parallel resonance with  $50\Omega$  maximum equivalent series resonance.

#### **Crystal Load Capacitors**

The device crystal connections should include pads for small capacitors from X1 to ground and from X2 to ground. These capacitors are used to adjust the stray capacitance of the board to match the nominally required crystal load capacitance. Because load capacitance can only be increased in this trimming process, it is important to keep stray capacitance to a minimum by using very short PCB traces (and no vias) between the crystal and device. Crystal capacitors must be connected from each of the pins X1 and X2 to ground.

The crystal cpacitors are internal to the device and have an effective value of 8pF.

#### Reference Pre-Divider, Reference Divider, Feedback-Divider and Post-Divider

Each PLL incorporates an 8-bit reference-scaler and a 11-bit feedback divider which allows the user to generate four unique non-integer-related frequencies. PLLA and PLLD each have a feedback pre-divider that provides additional multiplication for kHz reference clock applications. Each output divider supports 8-bit post-divider. The following equation governs how the output frequency is calculated.

$$F_{OUT} = \frac{F_{IN} * \left(\frac{A * M}{D}\right)}{ODIV} \quad (Eq. 2)$$

Where  $F_{IN}$  is the reference frequency, A is the feedback pre-divider value, M is the feedback-divider value, D is the reference divider value, ODIV is the total post-divider value, and  $F_{OUT}$  is the resulting output frequency. Programming any of the dividers may cause glitches on the outputs.

# SPREAD SPECTRUM GENERATION (PLLB)

PLLB has spread spectrum generation capability, which users have the option of turning on and off. Spread spectrum profile, frequency, and spread are fully programmable (within limits). The programmable spread spectrum generation parameters are NC[10:0], MOD[12:0], and NSS[10:0] bits. To enable spread spectrum, set SSENB\_B=0.

The spread spectrum circuitry was specifically developed to accommodate video display applications. The spread modulation frequency can be defined to exactly equal the horizontal line frequency (HSYNC)

#### NC[10:0]

These bits are used to determine the number of pulses per spread spectrum cycle. For video applications, NC is the number of pixels on the horizontal display row (or integer multiple of displayed pixels in a row). By matching the spread period to the screen, no tearing or "shimmer" will be apparent.

NC must be an even number to insure that the upward spread transition has the same number of steps as the downward spread transition.

For non-video applications, this can also be seen as the number of clock cycles for a complete spread spectrum period.

#### MOD[12:0]

These bits relate the VCO frequency to the target average spread output frequency ( $F_{MID}$ ).

 $F_{MID} = (F_{VCO}) / 8$ 

 $F_{MAX} = F_{MID} + (SS\% * F_{MID})$ 

 $F_{MIN} = F_{MID} - (SS\% * F_{MID})$ 

 $MOD = (F_{REF}^* NC) / (2 * F_{MID})$ 

### NSS[10:0]

These bits control the amplitude of the spread modulation.

 $NSS = (NC / 2) + (NC / 8) * (F_{MAX} - F_{MIN}) / F_{MID}$ 

#### Modulation frequency:

 $F_{MOD} = F_{MID} / NC (Eq. 11)$ 

### Video Example

 $F_{REF}$  = 27 MHz,  $F_{OUT}$  = 27 MHz, 640 pixels per line, center spread of ±1%. Using  $F_{VCO}$ =432MHz, find the necessary spread spectrum register settings.

 $F_{MID} = F_{VCO}/8$ 

NC = 640 (integer number of spread periods/screen)

MOD = (25MHz \* 640)/(2 \* 54MHz) = 160

NSS = (640/2)+(640/8)\*(27.27MHz-26.73MHz)/27MHz = 321.

 $F_{MOD} = 27MHz/640 = 11.8kHz.$ 

#### Non-Video Example

 $F_{REF}$  = 25MHz,  $F_{OUT}$  = 27 MHz, 31.25kHz modulation rate, center spread of ±1%. Find the necessary spread spectrum register settings.

 $F_{MID} = F_{VCO}/8$ 

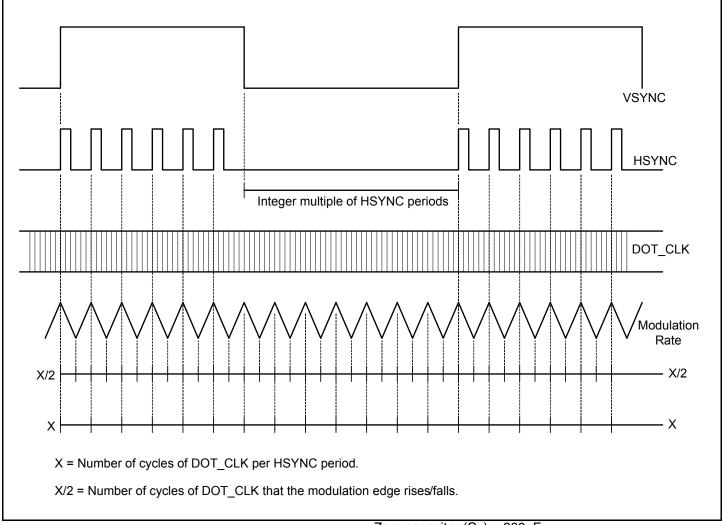
 $F_{MOD} = 31.25 \text{kHz} = 50.625 \text{MHz/NC}.$ 

NC = 1620

MOD = (25MHz \* 1620)/(2 \* 50.625MHz) = 400

NSS = (1620/2)+(1620/8)\*(27.27MHz-26.73MHz)/27MHz = 814.

### VSYNC, HSYNC, DOT\_CLK – Modulation Rate Relationship



#### LOOP FILTER

The loop filter for each PLL can be programmed to optimize the jitter performance. The low-pass frequency response of the PLL is the mechanism that dictates the jitter transfer characteristics. The loop bandwidth can be extracted from the jitter transfer. A narrow loop bandwidth is good for jitter attenuation while a wide loop bandwidth is best for low jitter generation. The specific loop filter components that can be programmed are the resistor via the RZ[4:0] bits, zero capacitor via the CZ[2:0] bits, pole capacitor via the CP[1:0] bits, and the charge pump current via the IP#[2:0] bits.

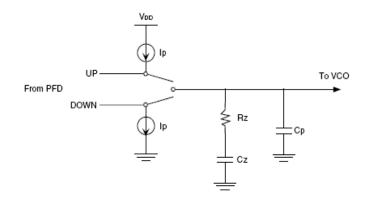
The following equations govern how the loop filter is set:

Zero capacitor (Cz) = 280pF

Pole capacitor (Cp) = 30pF

Charge pump (Ip) = IP#[2:0] uA

VCO gain (Kvco) =  $300MHz/V * 2\pi$ 



#### PLL Loop Bandwidth:

Charge pump gain  $(K\phi)$  = Ip /  $2\pi$ 

VCO gain (Kvco) = 950MHz/V \*  $2\pi$ 

M = Total multiplier value (See the PRE-SCALERS, FEEDBACK-DIVIDERS, POST-DIVIDERS section for more detail)

$$\omega c = (Rz * K\phi * Kvco * Cz)/(M * (Cz + Cp))$$

 $Fc = \omega c / 2\pi$ 

Note, the phase/frequency detector frequency (FPFD) is typically seven times the PLL closed-loop bandwidth (Fc) but too high of a ratio will reduce your phase margin thus compromising loop stability.

To determine if the loop is stable, the phase margin ( $\phi$ m) would need to be calculated as follows.

#### Phase Margin:

 $\omega z = 1 / (Rz * Cz)$ 

 $\omega p = (Cz + Cp)/(Rz * Cz * Cp)$ 

 $\phi m = (360 / 2\pi) * [tan^{-1}(\omega c / \omega z) - tan^{-1}(\omega c / \omega p)]$ 

To ensure stability in the loop, the phase margin is recommended to be >  $60^{\circ}$  but too high will result in the lock time being excessively long. Certain loop filter parameters would need to be compromised to not only meet a required loop bandwidth but to also maintain loop stability.

#### Example

Fc = 150KHz is the desired loop bandwidth. The total A\*M value is 160. The  $\zeta$ (damping factor) target should be 0.7, meaning the loop is critically damped. Given Fc and A\*M, an optimal loop filter setting needs to be solved for that will meet both the PLL loop bandwidth and maintain loop stability.

Choose a mid-range charge pump from register table

Icp= 11.9uA.

Ko \* Kvco = 300MHz/V \* 40uA = 12000A/Vs

 $\omega c = 2\pi * Fc = 9.42x10^{5} s^{-1}$ 

 $\omega p = (Cz + Cp)/(Rz * Cz * Cp) = \omega z (1 + Cz / Cp)$ 

Solving for Rz, the best possible value Rz=30kOhms (RZ[1:0]=10) gives

ζ= 1.2

Solving back for the PLL loop bandwidth, Fc=149kHz.

The phase margin must be checked for loop stability.

 $\phi m = (360 / 2\pi) * [tan_1 (9.42x10^5 s^{-1} / 1.19x10^5 s^{-1}) - tan^{-1} (9.42x10^5 s^{-1} / 1.23x10^6 s^{-1})] = 45^{\circ}$ 

The phase margin would be acceptable with a fairly stable loop.

# SEL[1:0] Function

The IDT5P49EE601 can support up to three unique configurations. Users may pre-programmed all these configurations, and select the configurations using SEL[1:0] pins. Alternatively, users may use I2C interface to configure these registers on- the-fly.

Power Down/Sleep Mode is selected by the No PD bit. No PD=0 enables Power Down mode with no outputs. No PD=1 enables sleep mode with 32kHz output on OUT2.

SEL1	SEL0	Configuration Selections
0	0	Power Down/Sleep Mode
0	1	Select CONFIG0
1	0	Select CONFIG1
1	1	Select CONFIG2

### **Configuration OUTx IO Standard**

Users can configure the individual output IO standard from a single 3.3V power supply. Each output can support 1.8V/

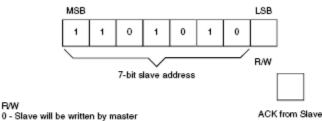
### **Programming the Device**

I<sup>2</sup>C may be used to program the IDT5P49EE601.

- Device (slave) address = 7'b1101010

### I<sup>2</sup>C Programming

The IDT5P49EE601 is programmed through an I2C-Bus serial interface, and is an I2C slave device. The read and write transfer formats are supported. The first byte of data after a write frame to the correct slave address is interpreted as the register address; this address auto-increments after each byte written or read.



1 - Slave will be read by master

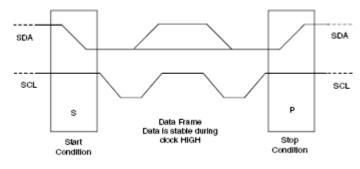
R/W

The first byte transmitted by the Master is the Slave Address followed by the R/W bit. The Slave acknowledges by sending a "1" bit.

### First Byte Transmitted on I<sup>2</sup>C Bus

2.5V or 3.3V LVCMOS. Output pair OUT4A/OUT4B can be configured to support an LVDS output. For LVDS support, VDDO1 must be set to 3.3V. VDDO1 must have the highest voltage of any pin on the device. VDDO2 and VDDO3 may have any value between 1.8V and VDDO1.

The frame formats are shown in the following illustration.



Framing

#### External I<sup>2</sup>C Interface Condition

KEY:

From Master to Slave

From Master to Slave, but can be omitted if followed by the correct sequence

Normally data transfer is terminated by a STOP condition generated by the Master. However, if the Master still wishes to communicate on the bus, it can generate a repeated START condition, and address another Slave address without first generating a STOP condition.

From Slave to Master

#### SYMBOLS:

ACK - Acknowledge (SDA LOW) NACK - Not Acknowledge (SDA HIGH) Sr - Repeated Start Condition S - START Condition

P-STOP Condition

#### **EEPROM Interface**

The IDT5P49EE601 can store its configuration in an internal EEPROM. The contents of the device's internal programming registers can be saved to the EEPROM by issuing a save instruction (ProgSave) and can be loaded back to the internal programming registers by issuing a restore instruction (ProgRestore).

To initiate a save or restore using  $I^2C$ , only two bytes are transferred. The Device Address is issued with the read/write bit set to "0", followed by the appropriate command code. The save or restore instruction executes

after the STOP condition is issued by the Master, during which time the IDT5P49EE601 will not generate Acknowledge bits. The IDT5P49EE601 will acknowledge the instructions after it has completed execution of them. During that time, the  $I^2C$  bus should be interpreted as busy by all other users of the bus.

On power-up of the IDT5P49EE601, an automatic restore is performed to load the EEPROM contents into the internal programming registers. The IDT5P49EE601 will be ready to accept a programming instruction once it acknowledges its 7-bit I<sup>2</sup>C address.

#### Progwrite

s	Address	R/W	ACK	Command Code	ACK	Register	ACK	Data	ACK	Р
	7-bits	0	1-bit	8-bits: xxxxxx00	1-bit	8-bits	1-bit	8-bits	1-bit	

#### **Progwrite Command Frame**

Writes can continue as long as a Stop condition is not sent and each byte will increment the register address.

#### Progread

Note: If the expected read command is not from the next higher register to the previous read or write command, then set a known "read" register address prior to a read operation by issuing the following command:

s	Address	R/W	ACK	Command Code	ACK	Register	ACK	$\mathbb{Z}$
	7-bits	0	1-bit	8-bits: xxxxxx00	1-bit	8-bits	1-bit	//

#### Prior to Progread Command Set Register Address

The user can ignore the STOP condition above and use a repeated START condition instead, straight after the slave acknowledgement bit (i.e., followed by the Progread command):

s	r Address	R/W	ACK	ID Byte	ACK	Data_1	ACK	Data_2	ACK	Data_last	NACK	Р
Γ	7-bits	1	1-bit	8 bits	1-bit	8-bits	1-bit	8-bits	1-bit	8-bits	1-bit	

#### **Progread Command Frame**

#### Progsave

s	Address	R/W	ACK	Command Code	ACK	Р
	7-bits	0	1-bit	8-bits:xxxxxx01	1-bit	

Note:

PROGWRITE is for writing to the IDT5P49EE601 registers. PROGREAD is for reading the IDT5P49EE601 registers. PROGSAVE is for saving all the contents of the IDT5P49EE601 registers to the EEPROM. PROGRESTORE is for loading the entire EEPROM contents to the IDT5P49EE601 registers.

#### Progrestore

s	Address	R/W	ACK	Command Code	ACK	Р
	7-bits	0	1-bit	8-bits:xxxxxx10	1-bit	

During PROGRESTORE, outputs will be turned off to ensure that no improper voltage levels are experienced before initialization.

# I<sup>2</sup>C Bus DC Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>IH</sub>	Input HIGH Level		0.7xVDD		5.5	V
V <sub>IL</sub>	Input LOW Level				0.3xVDD	V
V <sub>HYS</sub>	Hysteresis of Inputs		0.05xVDD			V
I <sub>IN</sub>	Input Leakage Current	$V_{DD} = 0V$			±1.0	μA
V <sub>OL</sub>	Output LOW Voltage	I <sub>OL</sub> = 3 mA			0.4	V

# I<sup>2</sup>C Bus AC Characteristics for Standard Mode<sup>1</sup>

Symbol	Parameter	Min	Тур	Max	Unit
F <sub>SCLK</sub>	Serial Clock Frequency (SCL)	0		100	kHz
t <sub>BUF</sub>	Bus free time between STOP and START	4.7			μs
t <sub>SU:START</sub>	Setup Time, START	4.7			μs
t <sub>HD:START</sub>	Hold Time, START	4			μs
t <sub>SU:DATA</sub>	Setup Time, data input (SDA)	250			ns
t <sub>HD:DATA</sub>	Hold Time, data input (SDA) <sup>1</sup>	0			μs
t <sub>OVD</sub>	Output data valid from clock			3.45	μs
CB	Capacitive Load for Each Bus Line			400	pF
t <sub>R</sub>	Rise Time, data and clock (SDA, SCLK)			1000	ns
t <sub>F</sub>	Fall Time, data and clock (SDA, SCLK)			300	ns
t <sub>HIGH</sub>	HIGH Time, clock (SCLK)	4			μs
t <sub>LOW</sub>	LOW Time, clock (SCLK)	4.7			μs
t <sub>SU:STOP</sub>	Setup Time, STOP	4			μs

#### 1) No activity is allowed on $I^2C$ lines until VDD>1.62V.

2) A device must internally provide a hold time of at least 300 ns for the SDA signal (referred to the V<sub>IH</sub>MIN of the SCLK signal) to bridge the undefined region of the falling edge of SCLK.

# I<sup>2</sup>C Bus AC Characteristics for Fast Mode<sup>1</sup>

Symbol	Parameter	Min	Тур	Max	Unit
F <sub>SCLK</sub>	Serial Clock Frequency (SCL)	0		400	kHz
t <sub>BUF</sub>	Bus free time between STOP and START	1.3			μs
t <sub>SU:START</sub>	Setup Time, START	0.6			μs
t <sub>HD:START</sub>	Hold Time, START	0.6			μs
t <sub>SU:DATA</sub>	Setup Time, data input (SDA)	100			ns
t <sub>HD:DATA</sub>	Hold Time, data input (SDA) <sup>1</sup>	0			μs
t <sub>OVD</sub>	Output data valid from clock			0.9	μs
CB	Capacitive Load for Each Bus Line			400	pF
t <sub>R</sub>	Rise Time, data and clock (SDA, SCL)	20 + 0.1xC <sub>B</sub>		300	ns
t <sub>F</sub>	Fall Time, data and clock (SDA, SCL)	20 + 0.1xC <sub>B</sub>		300	ns
t <sub>HIGH</sub>	HIGH Time, clock (SCL)	0.6			μs
t <sub>LOW</sub>	LOW Time, clock (SCL)	1.3			μs
t <sub>SU:STOP</sub>	Setup Time, STOP	0.6			μs

#### 1) No activity is allowed on $I^2C$ lines until VDD>1.62V.

2) A device must internally provide a hold time of at least 300 ns for the SDA signal (referred to the V<sub>IH</sub>MIN of the SCL signal) to bridge the undefined region of the falling edge of SCL.

### Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the IDT5P49EE601. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Symbol	Description	Мах	Unit
V <sub>DD</sub>	Internal Power Supply Voltage	-0.5 to +4.6	V
VI	Input Voltage	-0.5 to +4.6	V
V <sub>O</sub>	Output Voltage (not to exceed 4.6 V)	-0.5 to V <sub>DD</sub> +0.5	V
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C

### **Recommended Operation Conditions**

Symbol	Parameter	Min	Тур	Max	Unit
V <sub>DD</sub>	Power supply voltage for VDD closest to LVTTL and core	3	3.3	3.6	V
	Power supply voltage for VDD closest to LVDS outputs	3.135	3.3	3.465	
T <sub>A</sub>	Operating temperature, ambient	-40		+85	°C
C <sub>LOAD_OUT</sub>	Maximum load capacitance (3.3V LVTTL only)			15	pF
C <sub>LOAD_OUT</sub>	Maximum load capacitance (1.8V or 2.5V LVTTL only)			8	pF
F <sub>IN</sub>	External reference crystal	8		30	MHz
	External reference clock CLKIN	1		40	
t <sub>PU</sub>	Power up time for all $V_{\text{DD}}\text{s}$ to reach minimum specified voltage (power ramps must be monotonic)	0.05		5	ms

### **Capacitance** ( $T_A = +25 \text{ °C}$ , f = 1 MHz, $V_{IN} = 0V$ )

Symbol	Symbol Parameter		Тур	Max	Unit	
C <sub>IN</sub>	nput Capacitance		3		pF	
Crystal Specifications						
XTAL_FREQ	Crystal frequency	8		30	MHz	
XTAL_MIN	Minimum crystal load capacitance		TBD		pF	
XTAL_MAX	Maximum crystal load capacitance		35.4		pF	
XTAL_V <sub>PP</sub>	Voltage swing (peak-to-peak, nominal)	1.5	2.3	3.2	V	

# DC Electrical Characteristics for 3.3 Volt LVTTL<sup>1</sup>

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V <sub>OH</sub>	Output HIGH Voltage	I <sub>OH</sub> = 33mA	2.4		VDDO	V
V <sub>OL</sub>	Output LOW Voltage	I <sub>OH</sub> = 33mA			0.4	V
V <sub>IH</sub>	Input HIGH Voltage		2			V
V <sub>IL</sub>	Input LOW Voltage				0.8	V
I <sub>OZDD</sub>	Output Leakage Current	3-state outputs			5	μA

# DC Electrical Characteristics for 2.5Volt LVTTL<sup>1</sup>

Symbol	Parameter	Test Conditions	Min	Тур	Мах	Unit
V <sub>OH</sub>	Output HIGH Voltage	I <sub>OH</sub> = 25mA	2.1		VDDO	V
V <sub>OL</sub>	Output LOW Voltage	I <sub>OH</sub> = 25mA			0.4	V
I <sub>OZDD</sub>	Output Leakage Current	3-state outputs			5	μA

# DC Electrical Characteristics for 1.8Volt LVTTL<sup>1</sup>

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V <sub>OH</sub>	Output HIGH Voltage	VDD = 1.71V to 1.89V	0.65*VDDO		VDDO	V
V <sub>OL</sub>	Output LOW Voltage				0.35*VDDO	V
I <sub>OZDD</sub>	Output Leakage Current	3-state outputs			5	μA

### **Power Supply Characteristics for LVTTL Outputs**

Symbol	Parameter	Test Conditions	Тур	Max	Unit
I <sub>TOT</sub>	Total Power VDD Supply Current	$F_{REFERENCE CLOCK} = 25 \text{ MHz}, C_{L} = 7 \text{ pF}$	TBD		mA

Note 1: See "Recommended Operating Conditions" table. Alway completely power up VDD and VDDx prior to applying VDDO power.

### **DC Electrical Characteristics for LVDS**

Symbol	Parameter	Min	Тур	Max	Unit
V <sub>OT</sub> (+)	Differential Output Voltage for the TRUE binary state	247		454	mV
V <sub>OT</sub> (-)	Differential Output Voltage for the FALSE binary state	-247		-454	mV
$\triangle V_{OT}$	Change in V <sub>OT</sub> between Complimentary Output States			50	mV
V <sub>OS</sub>	Output Common Mode Voltage (Offset Voltage)	1.125	1.2	1.375	V
$\triangle V_{OS}$	Change in V <sub>OS</sub> between Complimentary Output States			50	mV
I <sub>OS</sub>	Outputs Short Circuit Current, $V_{OUT}$ + or $V_{OUT}$ = 0V or VDD		TBD	TBD	mA
I <sub>OSD</sub>	Differential Outputs Short Circuit Current, $V_{OUT}$ + = $V_{OUT}$ -		TBD	TBD	mA

# Power Supply Characteristics for LVDS Outputs<sup>1</sup>

Symbol	Parameter	Test Conditions <sup>2</sup>	Тур	Max	Unit
I <sub>DDQ</sub>	Quiescent VDD Power Supply Current	REF = LOW Outputs enabled, all outputs unloaded	TBD	TBD	mA
I <sub>DDD</sub>	Dynamic VDD Power Supply Current per Output	$VDD = Max., C_L = 0pF$	TBD	TBD	µA/MHz
I <sub>TOT</sub>	Total Power VDD Supply Current	$F_{REFERENCE CLOCK} = 25 \text{ MHz}, C_{L} = 5 \text{ pF}$	TBD	TBD	mA

1) OUT4A and OUT4B are toggling. Other outputs are powered down.

2) The termination resistors are excluded from these measurements.

# **AC Timing Electrical Characteristics**

(Spread Spectrum Generation = OFF)
------------------------------------

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
f <sub>IN</sub>	Input Frequency	Input Frequency Limit (CLKIN)	1 <sup>1</sup>		40	MHz
1 / t1	Output Frequency	Single Ended Clock output limit (LVTTL) 3.3V	0.001		120	MHz
		Single Ended Clock output limit (LVTTL) 2.5V			110	MHz
		Single Ended Clock output limit (LVTTL) 1.8V			100	MHz
		Differential Clock output limit (LVDS)			150	MHz
f <sub>VCO</sub>	VCO Frequency	VCO operating Frequency Range	100		500	MHz
f <sub>PFD</sub>	PFD Frequency	PFD operating Frequency Range	0.5 <sup>1</sup>		20	MHz
f <sub>BW</sub>	Loop Bandwidth	Based on loop filter resistor and capacitor values	0.01		10	MHz
t2	Input Duty Cycle	Duty Cycle for Input	40		60	%
t3	Output Duty Cycle	Measured at VDD/2	45		55	%
t4	Slew Rate, SLEWx(bits) = 00	Single-Ended 3.3V LVCMOS Output clock rise and fall time, 20% to 80% of VDD (Output Load = 7 pF)		3.5		V/ns
	Slew Rate, SLEWx(bits) = 01	Single-Ended 3.3V LVCMOS Output clock rise and fall time, 20% to 80% of VDD (Output Load = 7 pF)		2.75		-
	Slew Rate, SLEWx(bits) = 10	Single-Ended 3.3V LVCMOS Output clock rise and fall time, 20% to 80% of VDD (Output Load = 7 pF)		2		-
	Slew Rate, SLEWx(bits) = 11	Single-Ended 3.3V LVCMOS Output clock rise and fall time, 20% to 80% of VDD (Output Load = 7 pF)		1.25		
t5	Rise Times	LVDS, 20% to 80%		600		ps
	Fall Times			600		
t7	Clock Jitter	Peak-to-peak period jitter, CLK outputs measured at VDD/2; f <sub>PFD</sub> >= 10 MHz Single output frequency only.			100	ps
		Peak-to-peak period jitter, CLK outputs measured at VDD/2; f <sub>PFD</sub> >= 10 MHz Multiple output frequencies switching.			200	ps
t6	Output Skew	Skew between any output (Same freq and IO type, FOUT >10MHz)			200	ps
t7	Lock Time	PLL Lock Time from Power-up (using MHz reference clock) <sup>2</sup>		5	20	ms
		PLL Lock Time from Power-up using 32.768kHz reference clock)		1	3	S

1) Input clock (square wave) may be used at 1 MHz.

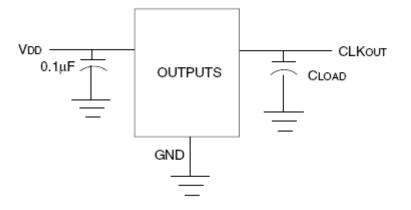
2) Time from supply voltage crosses VDD=1.62V to PLLs are locked.

### **Spread Spectrum Generation Specifications**

Symbol	Parameter	Description	Min	Тур	Max	Unit
f <sub>IN</sub>	Input Frequency	Input Frequency Limit	1 <sup>1</sup>		40	MHz
f <sub>MOD</sub>	Mod Frequency	Modulation Frequency	32		120	kHz
f <sub>SPREAD</sub>	Spread Value	Amount of Spread Value (programmable) - Down Spread	Programmable		able	%f <sub>OUT</sub>
		Amount of Spread Value (programmable) - Center Spread	Pro	gramm	able	

Note 1: Practical lower frequency is determined by loop filter settings.

## Test Circuits and Conditions<sup>1</sup>

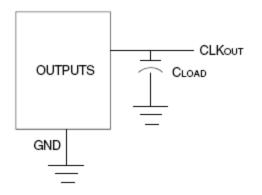


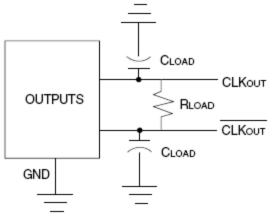
NOTE:

1. All Voo pins must be tied together.



### **Other Termination Scheme (Block Diagram)**





LVTTL: ~7pF for each output

LVDS:  $100\Omega$  between differential outputs with 5pF

# Programming Registers Table

	Default										
Addr	Register Hex Value	7 6 5 4 3		2	1 0		Description				
0x00	00	ONXTALB	CSX	2[1:0]	CSX	(1[1:0]	XTAL32ONB	Re	sserved	ONXTALB - MHz Crystal active low CSX2 [1:0]- internal 32kHz crystal cap2 00 - 18pF; 10 - 30pF 01 - 24pF; 11 - 36pF CSX1 [1:0] - Internal 32kHz crystal cap1 00 - 0pF; 10 - 6pF 01 - 3pF; 11 - 9pF XTAL32ONB - 32k crystal active low	
0x01	00	INV[0]	SLEW	0[0:1]	No_PD	P	S0[2:1]	Re	eserved	No_PD - Enables/Disables 32kHz	
0x02	00				Re	eserved				clock output on Config 00.	
0x03	00				Re	eserved				No_PD=0 - 32kHz is off. No_PD=1 - 32kHz remains active.	
0x04	00	INV[1]	SLEW	/1[0:1]	Reserved	PS	S1[2:1]	Re	eserved	INV[#] - Invert output#	
0x05	00				Re	eserved				SLEW#[0:1] - output# slew setting 0 0 - 5.1V/ns	
0x06	00				Re	eserved				0 0 - 5.1 V/NS 0 1 - 4.4V/ns	
0x07	00	INV[2]	SLEW	2[0:1]	Reserved	P	S22:1]	Re	eserved	1 0 - 2.8V/ns	
0x08	00	INV[3]	SLEW		Reserved	PS	S3[2:1]	Re	eserved	1 1 - 1.8V/ns PS#[2:1] -Power Select	
0x09	00	INV[4B]	INV[4A]	SLE\	00 - Reserved						
0x0A 0x0B	00	Reserved Reserved								01 - CLK# connects to VDDO1 10 - CLK# connects to VDDO2 11 - CLK# connects to VDDO3s	
0x0C	00				Re	eserved					
0x0D	00				Re	eserved					
0x0E	00		REFA[7:0]							Configuration0 REFA[7:0] - Reference Divide PLLA	
0x0F	00				FB	A[10:3)				FBA[10:0] - Feedback Divide PLLA	
0x10	00			Reserved				FBA[2:0)			
0x11	00	Reserved	XDIVA	RZ.	A[1:0]		IPA[2:0] REFSELA			XDIVA - FB predivide PLLA; 0 - /1; 1 - /4 RZA[1:0] - Zero Resistor PLLA 00 - 5kOhm 01 - 10kOhm 10 - 30kOhm 11 - 80kOhm IPA[2:0] - charge Pump Current PLLA 100 - 6.3uA 101 -11.9 uA 110 - 17.7 uA 111 - 22.7uA REFSELA - Clock input PLLA 0 - MHz input 1 - 32kHz input	
0x12	00					FB[7:0]				REFB[7:0] - Reference Divide PLLB	
0x13	00	FBB[10:3] FBB[10:0							FBB[10:0] - Feedback Divide PLLB		
0x14	00			MOD[4:0]				FBB[2:0]		PLLB Spread Parameters	
0x15	00					DD[12:5]				MOD[12:0] NC[10:0]	
0x16	00				N	C[10:3]				NSS[12:0]	
0x17	00			NSS[4:0]				NC[2:0]			
0x18	00				NS	SS[12:5]	·				

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#### IDT5P49EE601 VERSACLOCK<sup>®</sup> LOW POWER CLOCK GENERATOR

	Default															
Addr	Register Hex Value	7	6	5	4	3	2	1 0		Description						
0x19	20		Reserved			IPB[2:0]		RZ	B[1:0]	RZB[1:0] - Zero Resistor PLLB						
0x1A	00		Reserved REFSELB SSENB_B						Reserved         REFSELB         SSENB_B         00 - 5kOhm           01 - 10kOhm         10 - 30kOhm         10 - 30kOhm           11 - 80kOhm         11 - 80kOhm         11 - 80kOhm           11 - 80kOhm         10 - 6.3u/         001 - 1.1uA, 100 - 6.3u/           001 - 1.1uA, 101 - 11.9u/         001 - 1.8 uA, 110 - 17.7u         011 - 3.4uA, 111 - 22.7u/           REFSELB - Clock input         0 - MHz input         1 - 32kHz input							
0x1B	00					FC[7:0]				REFC[7:0] - Reference Divide PLLC						
0x1C	00				FB	C[10:3]	Т			FBC[10:0] - Feedback Divide PLLC						
0x1D	00			Reserved				FBC[2:0]								
0x1E	00					C2[7:0]				FBC2 - Feedback Predivide PLLC Turn on using XDIVC=1						
0x1F	00	IPC[2:0]				C[1:0]	Reserved	XDIVC	REFSELC	RZC[1:0] - Zero Resistor PLLC 00 - 5KOhm 01 - 10kOhm 10 - 30kOhm 11 - 80kOhm IPC[2:0] - charge Pump Current PLLC 100 - 6.3uA 101 -11.9 uA 110 - 17.7 uA 111 - 22.7uA REFSELC 0 - MHz input 1 - 32kHz input						
0x20	00				RE	FD[7:0]				REFD[7:0] - Reference Divide PLLD						
0x21	00		FBD[10:3]							FBD[10:0] - Feedback Divide PLLD						
0x22	00	Reserved FBD[2:0]														
0x23	00	XDIVD	XDIVD RZD[1:0]		IPD[2:0] REFSELD[1:0]		ELD[1:0]	XDIVD - FB predivide PLLD; 0 - /1; 1 - /4 RZD[1:0] - Zero Resistor PLLD 00 - 5kOhm 10 - 10kOhm 10 - 30kOhm 11 - 80kOhm IPD[2:0] - charge Pump Current PLLD 100 - 6.3uA 101 -11.9 uA 110 - 17.7 uA 111 - 22.7uA REFSELD[1:0] 00 - MHz input 11 - 32kHz input Others - Reserved								
0x24	00	OD0[7:0]							OD#[7:0] - Output Divide#							
0x25	00	Reserved														
0x26	00	Reserved														
0x27	00	OD1[7:0]														
0x28	00	Reserved														
0x29	00					eserved										
0x2A	00					D2[7:0]										
0x2B	00					D3[7:0]										
0x2C	00				0	D4[7:0]										

#### IDT5P49EE601 VERSACLOCK<sup>®</sup> LOW POWER CLOCK GENERATOR

	Default									
Addr	Register Hex Value	7	6	5	4	3	2	1	0	Description
0x2D	00	SCR4[1:0]		SCR			2[1:0]	Re	served	SRC4[1:0] - OD4 source 00 - off; 10 - PLLC 01 - PLLA; 11 - MHz Reference SRC3[1:0] - OD3 source 00 - off; 10 - PLLA 01 - PLLC; 11 - PLLB SRC2[1:0] - OD2 source 00 - off; 10 - MHz Reference 01 - PLLC; 11 - 32kHz Reference
0x2E	00	Rese	erved	SCR	1[1:0]	Res	erved	Re	served	SRC1[1:0] - OD1 source 00 - off; 10 - PLLB 01 - 32kHz Reference; 11 - PLLD
0x2F	00	SCR	0[1:0]			Re	eserved			SRC0[1:0] - OD0 source
0x30	00				Res	served				00 - off; 10 - PLLC 01 - PLLB; 11 - PLLD
0x31	00	PDB[4]	LVDS_ON	OE[4B]	OE[4A]		Re	served		PDB[#] - Powerdown OUT#.
0x32	00	OE[3]	OE[2]	Reserved	Reserved	OE[1]	Reserved	Reserved	OE[0]	PDB#=0, OUT# driven low OE[#] - Output enable OUT#.
0x33	00	PDB[3]	PDB[2]	Reserved	Reserved	PDB[1]	Reserved	Reserved	PDB[0]	OE#=0, OUT# tri-stated. If PDB#=OE#=0, OUT# driven low LVDS_ON 0 - OUT4A/OUT4B - LVCMOS outputs 1 - OUT4A/OUT4B -LVDS outputs. VDDO must be 3.3V
0x34	00					FA[7:0]				Configuration1 (See definitions from
0x35	00				FBA	A[10:3)				Configuration0 above)
0x36	00			Reserved				FBA[2:0)		
0x37	00	Reserved	XDIVA	RZA	[1:0]		IPA[2:0]		REFSELA	
0x38	00					FB[7:0]				
0x39	00				FBE	B[10:3]				
0x3A	00			MOD[4:0]				FBB[2:0]		
0x3B	00					D[12:5]				
0x3C	00				NC	2[10:3]	<b>T</b>			
0x3D	00			NSS[4:0]				NC[2:0]		
0x3E	00				NS	S[12:5]				
0x3F	40		Reserved			IPB[2:0]			B[1:0]	_
0x40	00			Hese	erved			REFSELB	SSENB_B	_
0x41	00					FC[7:0]				_
0x42 0x43	00	FBC[10:3]					_			
0x43 0x44	00			Reserved	ED(	C2[7:0]		FBC[2:0]		_
0x44 0x45	00		IPC[2:0]			[1:0]	Reserved	XDIV	REFSELC	4
0x45 0x46	00		11 0[2.0]			FD[7:0]	i lesel veu			-
0x40 0x47	00					D[10:3]				4
0x47 0x48	00			Reserved	i Di	-[]		FBD[2:0]		-
0x40	00	XDIVD	R7F	)[1:0]		IPD[2:0]			ELD[1:0]	
0x43 0x4A	00	OD0[7:0]								
0x4A 0x4B	00	Reserved								-
0x4C	00	Reserved								
0x4D	00					D1[7:0]				
0x4E	00					served				-
0x4F	00					served				-
0					. 100					

	Default	Bit #								
Addr	Register Hex Value	7	6	5	4	3	2	1	0	Description
0x50	00									
0x51	00				OD	3[7:0]				
0x52	00				OE	047:0]				
0x53	00		4[1:0]		3[1:0]		R21:0]		served	
0x54	00		erved	SCR	1[1:0]		served	Res	served	
0x55	00	SCR	0[1:0]			R	eserved			
0x56	00					served				
0x57	00	PDB[4]	LVDS_ON	OE[4B]	OE[4A]		Res	served		
0x58	00	OE[3]	OE[2]	Reserved	Reserved	OE[1]	Reserved	Reserved	OE[0]	
0x59	00	PDB[3]	PDB[2]	Reserved	Reserved	PDB[1]	Reserved	Reserved	PDB[0]	
0x5A	00				REI	FA[7:0]				Configuration2
0x5B	00				FBA	A[10:3)				(See definitions from Configuration0 above)
0x5C	00			Reserved				FBA[2:0)		comgaratione abore)
0x5D	00	Reserved	XDIVA	RZA	A[1:0]		IPA[2:0]		REFSELA	
0x5E	00				REF	=B[7:0]				
0x5F	00				FBE	3[10:3]				
0x60	00			MOD[4:0]				FBB[2:0]		
0x61	00				MO	D[12:5]				
0x62	00				NC	[10:3]				
0x63	00			NSS[4:0]				NC[2:0]		1
0x64	00				NS	S[12:5]				
0x65	40	Reserved IPB[2:0] RZB[1:0]							B[1:0]	
0x66	00			Res	erved			REFSELB	SSENB_B	
0x67	00				REF	-C[7:0]				
0x68	00				FBC	C[10:3]				
0x69	00			Reserved				FBC[2:0]		
0x6A	00					C2[7:0]				
0x6B	00		IPC[2:0]		RZC	[1:0]	Reserved	XDIV	REFSELC	
0x6C	00				REF	-D[7:0]				
0x6D	00				FBI	D[10:3]				
0x6E	00		Reserved FBD[2:0]							
0x6F	00	XDIVD	RZC	0[1:0]		IPD[2:0]		REFS	ELD[1:0]	
0x70	00				OD	00[7:0]				
0x71	00				Res	served				
0x72	00		Reserved							
0x73	00									
0x74	00									
0x75	00	Reserved								
0x76	00	OD2[7:0]								
0x77	00	OD3[7:0]								
0x78	00	OD4[7:0]								
0x79	00	SCR4[1:0]         SCR3[1:0]         SCR2[1:0]         Reserved								
0x7A	00	Reserved SCR1[1:0] Reserved Reserved								
0x7B	00	SCR0[1:0] Reserved								
0x7C	00					served				1
0x7D	00	PDB[4]	LVDS_ON	OE[4B]	OE[4A]		Res	served		1
0x7E	00	OE[3]	OE[2]	Reserved	Reserved	OE[1]	Reserved	Reserved	OE[0]	
0x7F	00	PDB[3]	PDB[2]	Reserved	Reserved	PDB[1]	Reserved	Reserved	PDB[0]	

### Marking Diagram (NL24)



Notes:

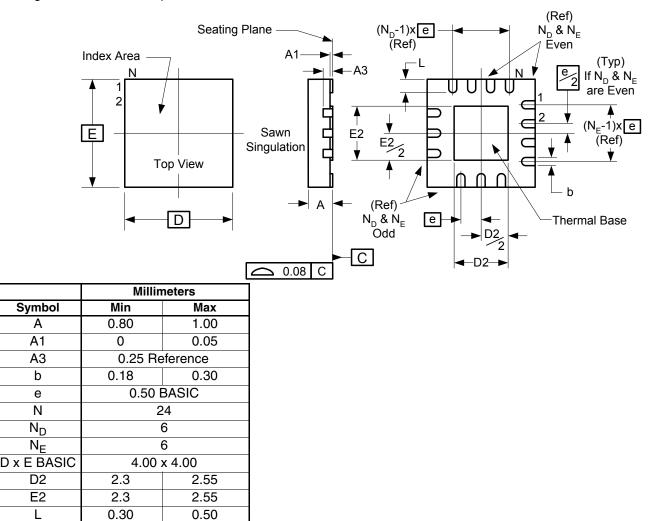
- 1. "Z" is the device step (1 to 2 characters).
- 2. YYWW is the last two digits of the year and week that the part was assembled.
- 3. "\$" is the assembly mark code.
- 4. "G" after the two-letter package code designates RoHS compliant package.
- 5. "I" at the end of part number indicates industrial temperature range.
- 6. Bottom marking: country of origin if not USA.

### **Thermal Characteristics for 24QFN**

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Thermal Resistance Junction to	$\theta_{JA}$	Still air		29.1		°C/W
Ambient	$\theta_{JA}$	1 m/s air flow		22.8		°C/W
	$\theta_{JA}$	2.5 m/s air flow		21.0		°C/W
Thermal Resistance Junction to Case	$\theta_{JC}$			41.8		°C/W

### Package Outline and Package Dimensions (24-pin 4mm x 4mm QFN)

Package dimensions are kept current with JEDEC Publication No. 95



### **Ordering Information**

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
5P49EE601NLGI	See Page 23	Tubes	24pin VFQFPN	-40 to +85° C
5P49EE601NLGI8	See Page 23	Tape and Reel	24pin VFQFPN	-40 to +85° C

Parts that are ordered with a "G" after the two-letter package code are the Pb-Free configuration and are RoHS compliant.

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### **Revision History**

Rev.	Originator	Date	Description of Change
	R.Willner	10/29/09	Preliminary Datasheet release.
А	R.Willner	11/20/09	No_PD bit inclusion - 32kHz clock on/off in Config 00.
В	R.Willner	3/25/10	Typographical changes. Correct spread spectrum calculations.
С	R.Willner	6/11/10	Typographical changes. Default configuration.

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